## Electronics

## Diodes, more circuits

Problem 1.- The following circuit is a model of a network of voltage and current sources. Use the second approximation of silicon diodes to find the current $\mathrm{I}_{\mathrm{D}}$.


Solution: All the linear components from the point of view of the diode can be replaced by a Thevenin equivalent with the values
$R_{T h}=820 / / 2.2 k+1 k=1.60 k \Omega$
$V_{T h}=25 \mathrm{~V}+15.9 \mathrm{~V}=40.9 \mathrm{~V}$

Then the current in the diode will be
$I_{D}=\frac{40.9 \mathrm{~V}-0.7 \mathrm{~V}}{1.6 \mathrm{k} \Omega}=\mathbf{2 5 . 1} \mathbf{m A}$
Problem 2.- In the circuit shown in the figure, calculate $\mathrm{V}_{\mathrm{L}}$. Consider the diode as ideal in first approximation.


Solution: The voltage $\mathrm{V}_{\mathrm{L}}$ can be calculated by simply multiplying the current through the 1 kohm by 1 kohm , but this current is the one going through the diode minus 25 mA . Then, we need to find the current through the diode first.

We start by converting the voltage source on the left side of the circuit into a current source:


This source has the value $I_{A C}=\frac{30 \cos \omega t}{820}=36.6 \mathrm{~mA} \cos \omega t$


Then we simplify the network of resistances and sources to get
$820 / / 2.2 k=597 \Omega$


And now we convert the two current sources into voltage sources.
$V_{1}=(10 \mathrm{~mA}+36.6 \mathrm{~mA} \cos \omega t)(0.597 \mathrm{kohm})=5.97 \mathrm{~V}+21.9 \mathrm{~V} \cos \omega t$
$V_{2}=(25 \mathrm{~mA})(1 \mathrm{kohm})=25 \mathrm{~V}$


Finally we add the sources in series:


Because the diode behaves as an ideal switch in first approximation, when the voltage is positive the current will be given by V/R and zero when the voltage is negative. Below is a sketch of the source voltage (blue, V) and current through the diode (red, mA), with the horizontal scale in multiples of $\omega t$.


Recall that the voltage in the load is obtained by subtracting 25 mA to the diode current and multiplying by 1 kohm . This is the final result:


Problem 3.- The circuit shown in the figure has a non-linear response due to the silicon diode. Considering the saw-tooth input signal given Vi , sketch the output signal $\mathrm{V}_{\mathrm{L}}$ indicating the point where the diode starts to conduct electricity and the peak values.
In your analysis consider the second approximation of the diode.
$\mathrm{r}_{\mathrm{i}}=100 \Omega, \quad \mathrm{R}_{\mathrm{b}}=100 \Omega, \quad \mathrm{R}_{\mathrm{L}}=100 \Omega$


Solution: First, let us find when the diode starts to conduct electricity. From its point of view, the Thevenin voltage is
$V_{T h}=V_{i} \frac{R_{b}}{R_{b}+r_{i}+R_{L}}=V_{i} \frac{100}{100+100+100}=0.333 V_{i}$
The diode will conduct when this value is less than -0.7 V , which means that
$0.333 V_{i}<-0.7 \rightarrow V_{i}<-2.1 V$

This point will separate the output signal in two cases:
i) If the input voltage is greater than -2.1 V the diode will behave as an open circuit and the output voltage will be:

$$
V_{L}=\frac{100}{100+100+100} V_{i}=0.333 V_{i}
$$

The positive peak will be $V_{L}=0.333(12)=4 V$
ii) If the input voltage is less than -2.1 V , the diode will behave as a 0.7 V voltage source and the output voltage will be:

$$
V_{L}=\frac{100}{100+100}\left(V_{i}+0.7\right)=0.5 V_{i}+0.35 \mathrm{~V}
$$

The negative peak will be $V_{L}=0.5(-12)+0.35=-5.65 \mathrm{~V}$

Notice that the transition point between cases i and ii is the same voltage, as expected:
(i) $V_{L}(-2.1)=0.333 V_{i}=0.333 \times(-2.1)=-0.7 \mathrm{~V}$
(ii) $V_{L}(-2.1)=0.5 V_{i}+0.35 V=0.5 \times(-2.1)+0.35=-1.05+0.35=-0.7 V$

Sketch of the output voltage:


Problem 4.- Sketch the load voltage in the circuit, given the input voltage shown in the figure. Approximate the diode as a 0.7 V drop in conduction.
$\mathrm{r}_{\mathrm{i}}=10 \Omega, \quad \mathrm{R}_{\mathrm{b}}=33 \Omega, \quad \mathrm{R}_{\mathrm{L}}=330 \Omega$



Problem 5.- In the circuit shown in the figure, calculate the voltage in the load resistor. The I-V curve of the diode can be described by the function:
$I_{D}=\left\{\begin{array}{cc}0.02 V_{D}{ }^{2} & V_{D}>0 \\ 0 & V_{D}<0\end{array}\right.$


